MOSPEC

MBRF10200CJ

SCHOTTKY BARRIER RECTIFIERS

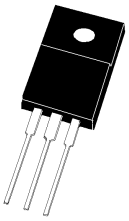
10 AMPERES
200 VOLTS

Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 175℃ junction temperature. Typical application are in switching Mode Power Supplies such as adaptors, DC/DC converters, free-wheeling and polarity protection diodes.

- ∗Low Forward Voltage.
- ∗Low Forward Voltage.
- ∗Low Switching noise.
- ∗High Current Capacity
- ∗Guarantee Reverse Avalanche.
- ∗Guard-Ring for Stress Protection.
- ∗Low Power Loss & High efficiency.
- ∗175℃ Operating Junction Temperature
- ∗Low Stored Charge Majority Carrier Conduction.
- ∗Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- ∗ESD: 4KV(Min.) Human-Body Model

∗ *In compliance with EU RoHs 2002/95/EC directives*



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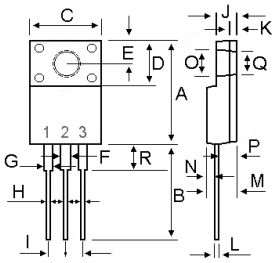
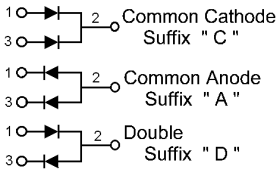


DIM	MILLIMETERS	
	MIN	MAX
A	14.90	15.15
B	13.35	13.55
C	10.00	10.30
D	6.55	6.65
E	2.65	2.75
F	1.60	1.75
G	1.20	1.47
H	0.55	0.65
I	2.50	2.60
J	3.00	3.20
K	1.10	1.20
L	0.55	0.65
M	4.40	4.60
N	1.15	1.25
O	3.35	3.45
P	2.65	2.75
Q	3.15	3.25
R	3.60	3.80



MAXIMUM RATINGS

Characteristic	Symbol	MBRF10200CJ	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	200	V
RMS Reverse Voltage	$V_{R(RMS)}$	140	V
Average Rectifier Forward Current Total Device (Rated V_R),	$I_{F(AV)}$	5.0 10	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	150	A
Operating and Storage Junction Temperature Range	T_J , T_{STG}	-65 to +175	℃

THERMAL RESISTANCES

Typical Thermal Resistance junction to case	$R_{\theta jc}$	5.2	℃/w

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	MBRF10200CJ	Unit
Maximum Instantaneous Forward Voltage (I_F =5.0 Amp T_C = 25℃) (I_F =5.0 Amp T_C = 125℃)	V_F	0.87 0.75	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T_C = 25℃) (Rated DC Voltage, T_C = 125℃)	I_R	0.5 1	uA mA

MBRF10200CJ

FIG-1 FORWARD CURRENT DERATING CURVE

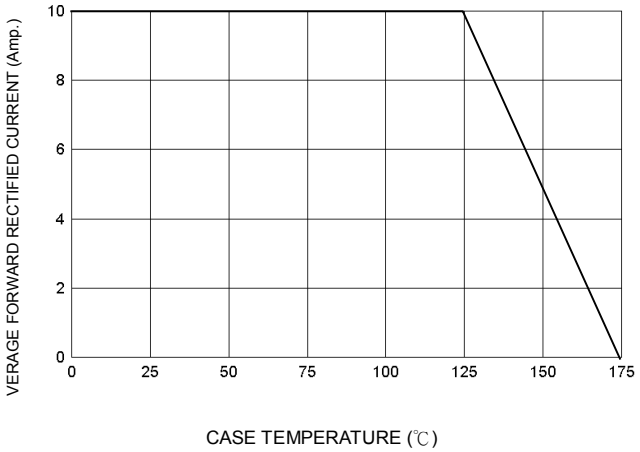


FIG-2 TYPICAL FORWARD CHARACTERISITICS

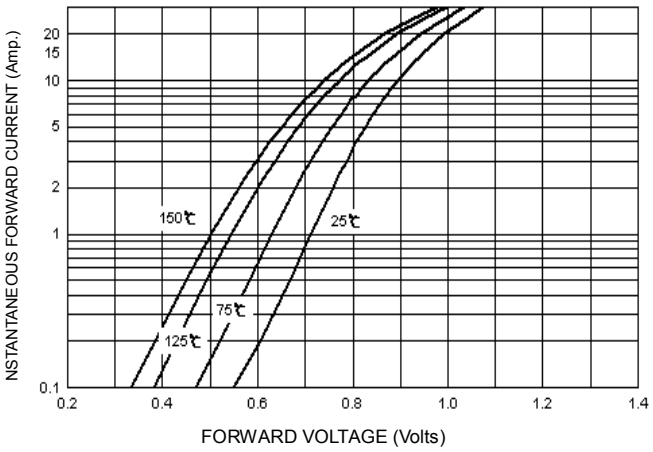


FIG-3 TYPICAL REVERSE CHARACTERISTICS

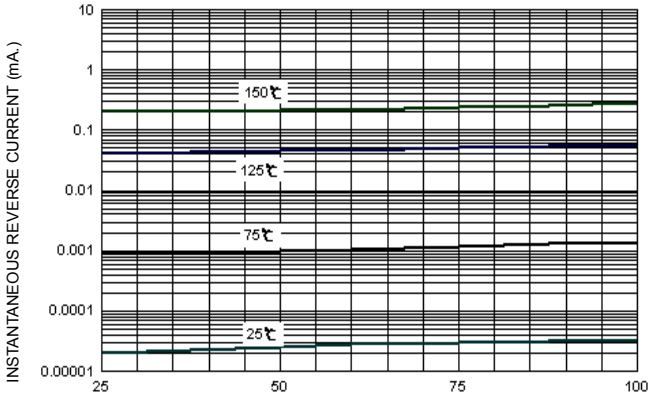


FIG-4 TYPICAL JUNCTION CAPACITANCE

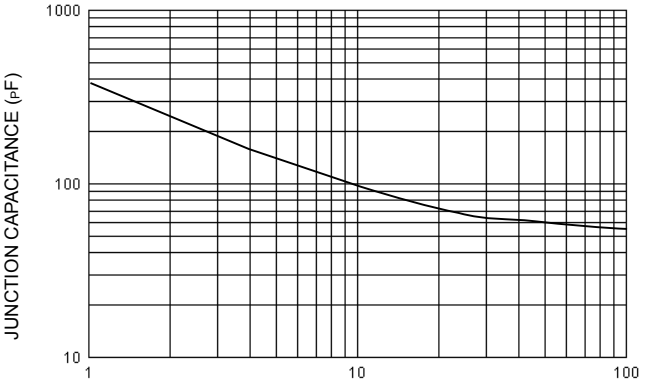
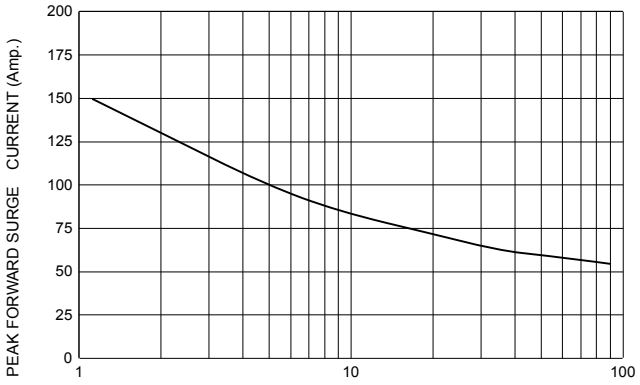


FIG-5 PEAK FORWARD SURGE CURRENT



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